



SINGLE N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(ON)} max	I _D max T _A = +25°C
	8mΩ @ V _{GS} = 10V	12A
20V	9mΩ @ V _{GS} = 4.5V	10A
	12mΩ @ V _{GS} = 2.5V	8A

Description and Applications

This MOSFET has been designed to minimize the on-state resistance (R_{DS(on)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

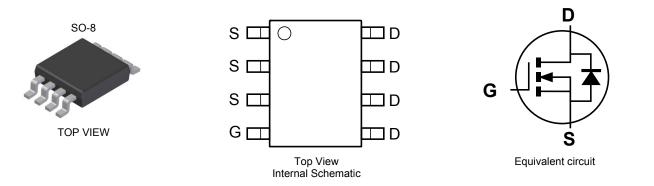
- Backlighting
- **Power Management Functions**
- **DC-DC Converters**

Features

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See diagram
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.074 grams (approximate)



Ordering Information (Note 4)

Part Number	Case	Packaging
DMN2009LSS-13	SO-8	2500/Tape & Reel

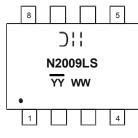
Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

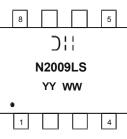
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



Chengdu A/T Site



Shanghai A/T Site

) | | = Manufacturer's Marking N2009LS = Product Type Marking Code YYWW = Date Code Marking YY or \overline{YY} = Year (ex: 13 = 2013) WW = Week (01 - 53) YY = Date Code Marking for SAT (Shanghai Assembly/ Test site) YY = Date Code Marking for CAT (Chengdu Assembly/ Test site)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Drain-Source Voltage			V _{DSS}	20	V
Gate-Source Voltage			V _{GSS}	±12	V
Drain Current (Note 5)	Steady State	T _A = +25°C T _A = +70°C	lD	12 9.6	A
Pulsed Drain Current (Note 6)			I _{DM}	42	А

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	2	W
Thermal Resistance, Junction to Ambient	$R_{ heta JA}$	62.5	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

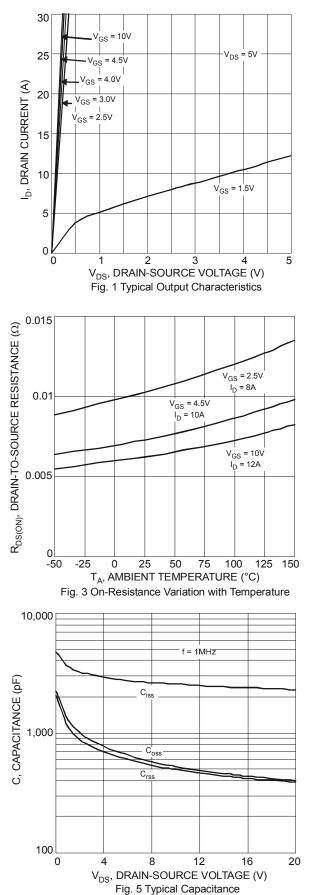
			_				
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	20	—		V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current	I _{DSS}		_	1	μA	V_{DS} = 20V, V_{GS} = 0V	
Gate-Source Leakage	I _{GSS}			±100	nA	$V_{GS} = \pm 12V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(th)}	0.5		1.2	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
				8		V _{GS} = 10V, I _D = 12A	
Static Drain-Source On-Resistance	R _{DS (ON)}	—	_	9	mΩ	V _{GS} = 4.5V, I _D = 10A	
				12		V _{GS} = 2.5V, I _D = 8A	
Forward Transconductance	g _{fs}		27	_	S	V _{DS} = 5V, I _D = 6.5A	
Diode Forward Voltage	V _{SD}	0.5	0.7	1.2	V	$V_{GS} = 0V, I_{S} = 3A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C _{iss}	_	2555	_	pF		
Output Capacitance	Coss	_	523	_	pF	V _{DS} = 10V, V _{GS} = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	_	496	_	pF		
Gate Resistance	R _G	_	1.1	_	Ω	$V_{GS} = 0V V_{DS} = 0V, f = 1MHz$	
SWITCHING CHARACTERISTICS (Note 8)							
Total Gate Charge	0		28.9			V _{DS} = 10V, V _{GS} = 4.5V, I _D = 12A	
	Qg		58.3		nC	V _{DS} = 10V, V _{GS} = 10V, I _D = 12A	
Gate-Source Charge	Q _{gs}		3.7	_	iiC	V_{DS} = 10V, V_{GS} = 10V, I_D = 12A	
Gate-Drain Charge	Q _{gd}		11.4	_	V _{DS} = 10V, V _{GS} = 10V, I _D = 12		

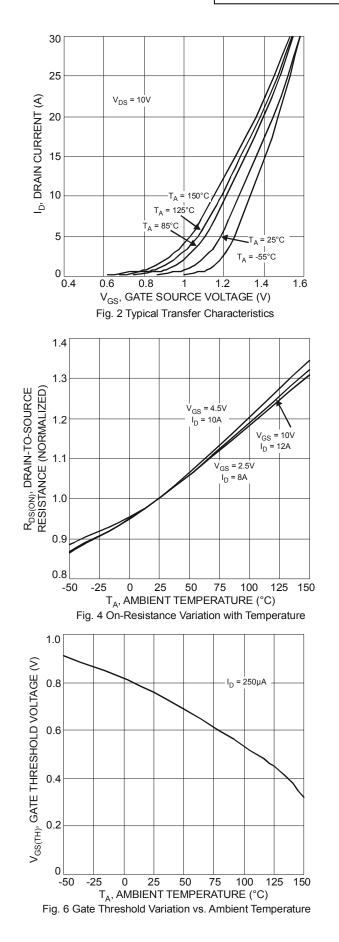
Notes: 5. Device mounted on 2 oz, FR-4 PCB, with $R_{\theta JA}$ = 62.5°C/W

Belies midth ≤10µS, Duty Cycle ≤1%.
Pulse width ≤10µS, Duty Cycle ≤1%.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.

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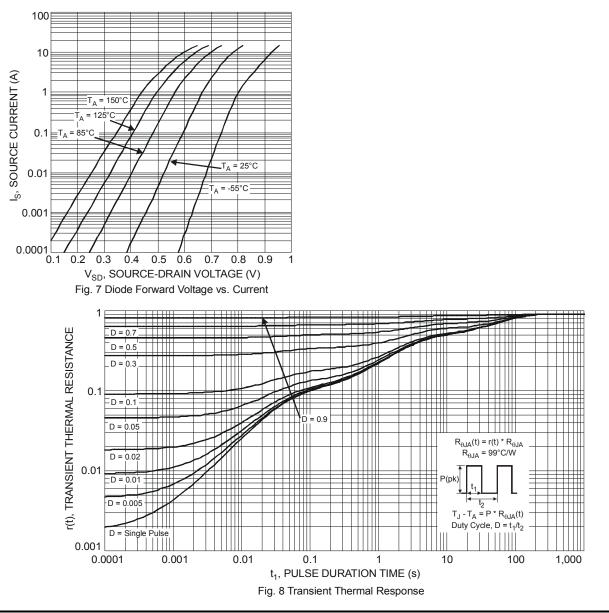






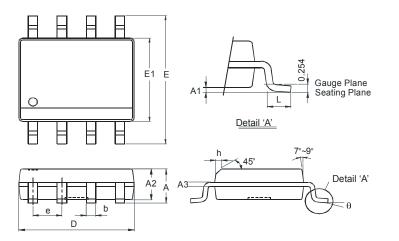
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Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

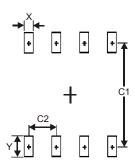


SO-8				
Dim	Min	Max		
Α	-	1.75		
A1	0.10	0.20		
A2	1.30	1.50		
A3	0.15	0.25		
b	0.3	0.5		
D	4.85	4.95		
ш	5.90	6.10		
E1	3.85	3.95		
e	1.27 Typ			
h	-	0.35		
L	0.62	0.82		
θ	0°	8°		
All Dimensions in mm				



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Х	0.60
Y	1.55
C1	5.4
C2	1.27

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